

Technology & Industry Alliances

Available Technologies

Contact Us

Permalink

Request Information

This technology is currently not available for licensing

Tech ID: 33478

ADDITIONAL TECHNOLOGIES BY THESE INVENTORS

- Vertical Cavity Surface-Emitting Lasers with Continuous Wave Operation
- Eliminating Misfit Dislocations with In-Situ Compliant Substrate Formation
- III-Nitride-Based Vertical Cavity Surface Emitting Laser (VCSEL) with a Dielectric P-Side Lens
- Ultraviolet Laser Diode on Nano-Porous AlGaN template
- Methods for Fabricating III-Nitride Tunnel Junction Devices
- Contact Architectures for Tunnel Junction Devices
- III-Nitride Tunnel Junction LED with High Wall Plug Efficiency
- ▶ Novel Multilayer Structure for High-Efficiency UV and Far-UV Light-Emitting Devices
- A Method To Lift-Off Nitride Materials With Electrochemical Etch
- High-Intensity Solid State White Laser Diode
- Nitride Based Ultraviolet LED with an Ultraviolet Transparent Contact
- ▶ High-Efficiency and High-Power III-Nitride Devices Grown on or Above a Strain Relaxed Template
- ▶ III-Nitride Based VCSEL with Curved Mirror on P-Side of the Aperture

University of California, Santa Barbara Office of Technology & Industry Alliances 342 Lagoon Road, ,Santa Barbara,CA 93106-2055 | https://www.tia.ucsb.edu Tel: 805-893-2073 | Fax: 805.893.5236 | padilla@tia.ucsb.edu

in

© 2024, The Regents of the University of California Terms of use **Privacy Notice**